FAIRCHILD SEMICONDUCTOR® FDMA7672 Single N-Channel PowerTrench [®] I	April 2012
 30 V, 9 A, 21 mΩ Features Max r_{DS(on)} = 21 mΩ at V_{GS} = 10 V, I_D = 9 A Max r_{DS(on)} = 32 mΩ at V_{GS} = 4.5 V, I_D = 7 A Low Profile - 0.8 mm maximum - in the new package MicroFET 2x2 mm Free from halogenated compounds and antimony oxides RoHS compliant 	 General Description This device has been designed to provide maximum efficiency and thermal performance for synchronous buck converters. The low r_{DS(on)} and gate charge provide excellent switching performance. Application DC – DC Buck Converters
Pin 1 D D G Drain D D S D D S MicroFET 2X2 (Bottom View)	D D D D C C C C C C C C C C C C C C C C

MOSFET Maximum Ratings $T_A = 25 \ ^{\circ}C$ unless otherwise noted

Symbol		Parameter		Ratings	Units	
V _{DSS}	Drain to Source Voltage			30	V	
V _{GSS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous	T _A = 25 °C	(Note 1a)	9	٨	
D	-Pulsed			24	A	
Р	Power Dissipation	T _A = 25 °C	(Note 1a)	2.4	w	
PD	Power Dissipation	T _A = 25 °C	(Note 1b)	0.9	VV	
T _J , T _{STG}	Operating and Storage Junction Te	emperature Range		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	6.9	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1	a) 52	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Note 1	b) 145	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
672	FDMA7672	MicroFET 2x2	7 "	12 mm	3000 units

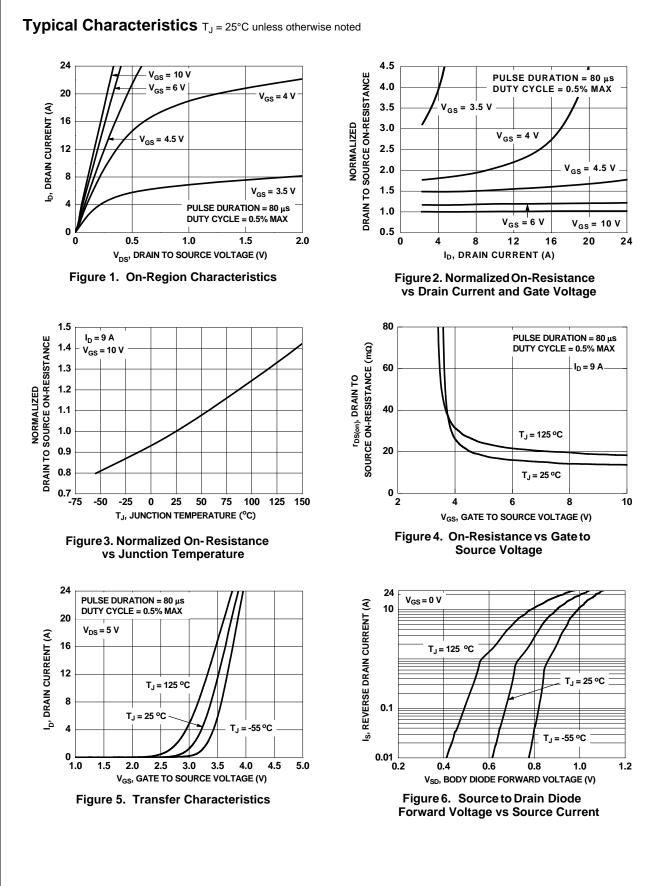
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	Parameter	Test Conditi	ons	Min	Тур	Max	Units
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	,	30			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu A$, reference			16		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$				1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$	1			100	nA
On Chara	acteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \ \mu$	A	1.0	2.1	3.0	V
$\Delta V_{GS(th)}$ ΔT_J	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C			-6		mV/°C
		$V_{GS} = 10 \text{ V}, I_{D} = 9 \text{ A}$		14	21		
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, \ I_D = 7 \text{ A}$		20	32	mΩ	
		V _{GS} = 10 V, I _D = 9 A, 1		19	28		
9 _{FS}	Forward Transconductance	V _{DS} = 5 V, I _D = 9 A			35		S
Dynamic	Characteristics						
C _{iss}	Input Capacitance				570	760	pF
C _{oss}	Output Capacitance	→ V _{DS} = 15 V, V _{GS} = 0 V - f = 1.0 MHz			195	260	pF
C _{rss}	Reverse Transfer Capacitance				25	40	pF
R _g	Gate Resistance				1.5		Ω
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time				6	12	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 9 A	-		2	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$			14	25	ns
t _f	Fall Time		-		2	10	ns
Q _g	Total Gate Charge	V _{GS} = 0 V to 10 V			9.3	13	nC
Q _g	Total Gate Charge		√ _{DD} = 15 V,		4.4	6	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 9 A		1.9		nC
Q _{gd}	Gate to Drain "Miller" Charge				1.5		nC
Drain-So	urce Diode Characteristics						
I _S	Maximum Continuous Drain-Source Diod	e Forward Current				2	A
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 2 A$	(Note 2)		0.8	1.2	V
- 30	Reverse Recovery Time		, ,		18	32	ns
t _{rr}	Reverse Recovery Charge	- I _F = 9 A, di/dt = 100 A/μs			5	10	nC

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

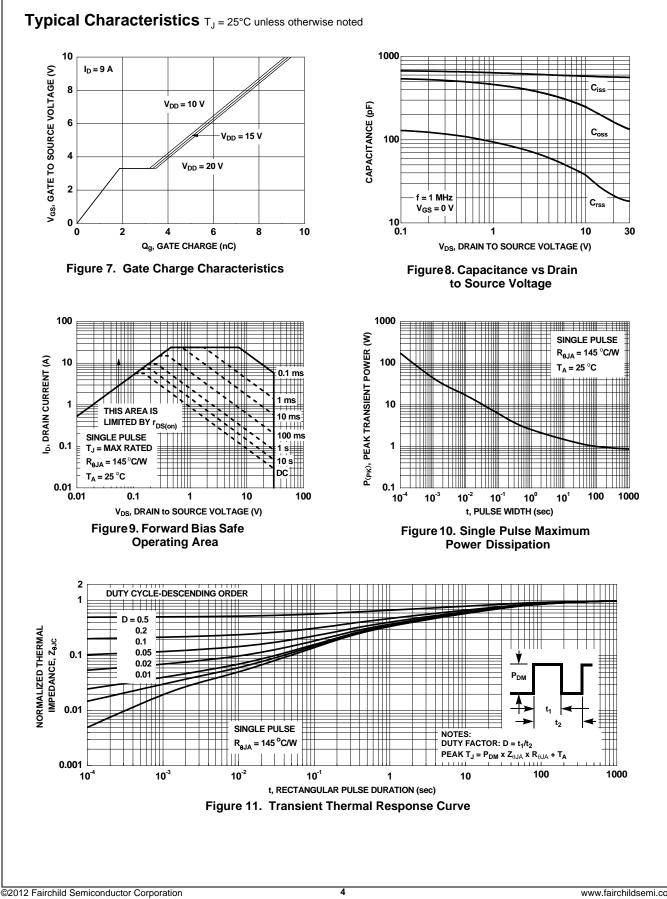
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FDMA7672 Single N-Channel Power Trench[®] MOSFET



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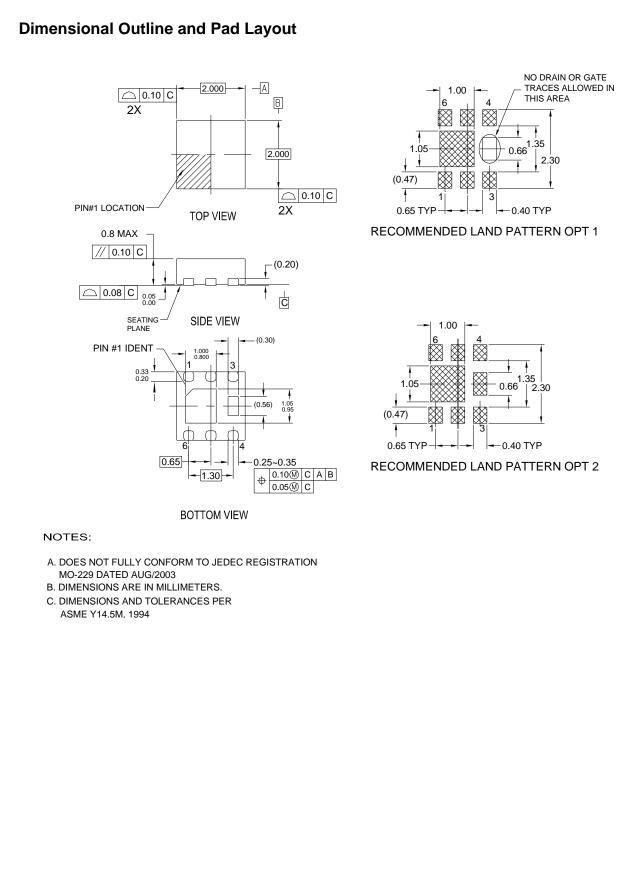
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